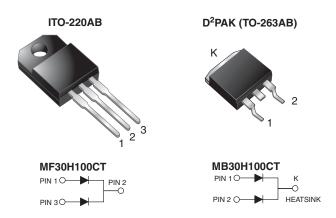


# MB30H100CT, MF30H100CT

Vishay General Semiconductor

# **Dual Common Cathode High Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	15 A x 2				
V <sub>RRM</sub>	100 V				
I <sub>FSM</sub> 275 А					
V <sub>F</sub>	0.67 V				
I <sub>R</sub>	5.0 µA				
T <sub>J</sub> max.	175 °C				
Package	ITO-220AB, D <sup>2</sup> PAK (TO-263AB)				
Circuit configuration	Common cathode				

#### **FEATURES**

- Power pack
- Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- · High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D<sup>2</sup>PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

#### **MECHANICAL DATA**

Case: ITO-220AB, D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code e.g. A, B, ....)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

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HE3 suffix meets JESD 201 class 2 whisker test

#### Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	MB30H100CT	UNIT	
Maximum repetitive peak reverse voltage	mum repetitive peak reverse voltage		100		
Working peak reverse voltage		V <sub>RWM</sub>	100	V	
Maximum DC blocking voltage		V <sub>DC</sub>	100		
Maximum average forward rectified current (fig.1)	total device	I <sub>F(AV)</sub>	30		
	per diode		15		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	275	A	
Peak repetitive reverse surge current per diode at $t_p = 2.0 \ \mu s$ , 1 kHz		I <sub>RRM</sub>	1.0		
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +175	°C	
Isolation voltage (ITO-220AB only) from terminal to heat sink t = 1 min		V <sub>AC</sub>	1500	V	

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_c = 25 \degree C$ unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> (1)	l <sub>F</sub> = 15 A	T <sub>J</sub> = 25 °C	0.82	- V	
		l <sub>F</sub> = 15 A	T <sub>J</sub> = 125 °C	0.67		
		I <sub>F</sub> = 30 A	T <sub>J</sub> = 25 °C	0.93		
		I <sub>F</sub> = 30 A	T <sub>J</sub> = 125 °C	0.80		
Maximum reverse current per diode	I <sub>R</sub> <sup>(2)</sup>	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	5.0	μA	
			T <sub>J</sub> = 125 °C	6.0	mA	

Note

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width,  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL	MB	MF	UNIT	
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	1.9	4.6	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	MF30H100CTHE3_B/P (1)	1.99	Р	50/tube	Tube	
TO-263AB	MB30H100CTHE3_B/P (1)	1.35	Р	50/tube	Tube	
TO-263AB	MB30H100CTHE3_B/I (1)	1.35	I	800/reel	Tape and reel	

Note

(1) AEC-Q101 qualified

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#### **RATINGS AND CHARACTERISTICS CURVES** ( $T_C = 25$ °C unless otherwise noted)

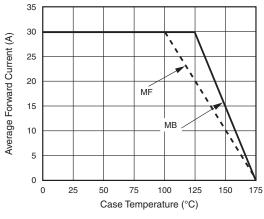


Fig. 1 - Forward Derating Curve Per Diode

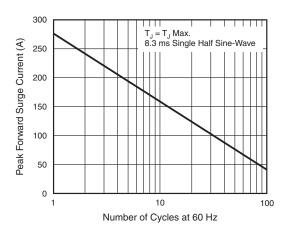


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

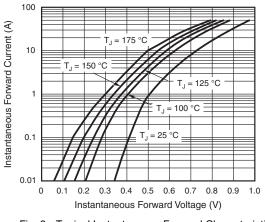


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

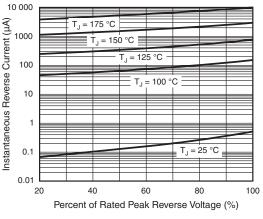
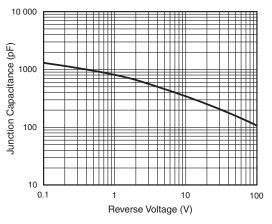
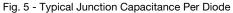


Fig. 4 - Typical Reverse Characteristics Per Diode





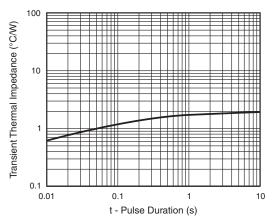


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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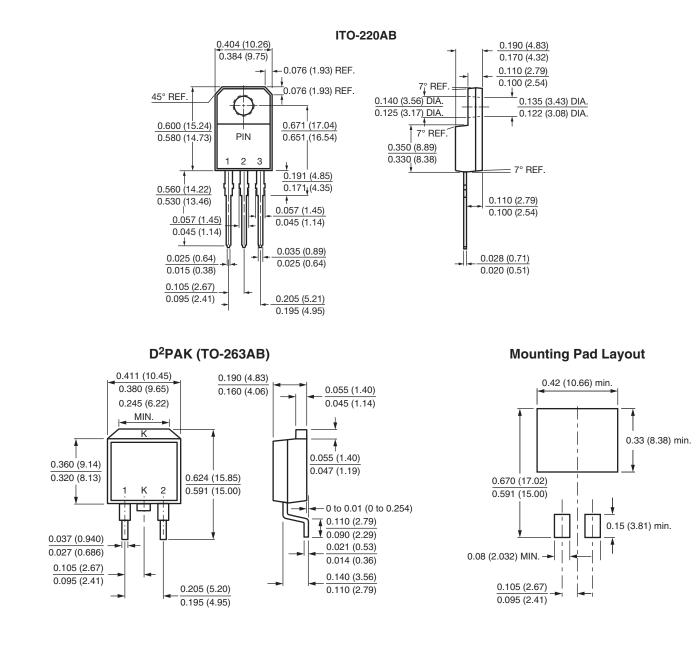
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#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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